

2SA1182

SILICON PNP EPITAXIAL TYPE

AUDIO FREQUENCY LOW POWER AMPLIFIER APPLICATIONS

DRIVER STAGE AMPLIFIER APPLICATIONS

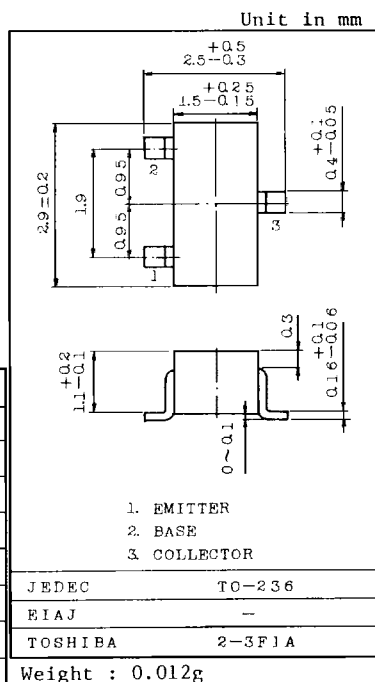
SWITCHING APPLICATIONS

FEATURES:

- Excellent h_{FE} Linearity: $h_{FE}(2)=25(\text{Min.})$ at $V_{CE}=-6V$ $I_C=-400\text{mA}$
- Complementary to 2SC2859.

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-35	V
Collector-Emitter Voltage	V_{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-500	mA
Base Current	I_B	-50	mA
Collector Power Dissipation	P_C	150	mW
Junction Temperature	T_j	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~125	$^\circ\text{C}$



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=-35V$, $I_E=0$	-	-	-0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-5V$, $I_C=0$	-	-	-0.1	μA
DC Current Gain (Note)	$h_{FE}(1)$	$V_{CE}=-1V$, $I_C=-100\text{mA}$	70	-	240	
	$h_{FE}(2)$	$V_{CE}=-6V$, $I_C=-400\text{mA}$	25	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-100\text{mA}$, $I_B=-10\text{mA}$	-	-0.1	-0.25	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=-1V$, $I_C=-100\text{mA}$	-	-0.8	-1.0	V
Transition Frequency	f_T	$V_{CE}=-6V$, $I_C=-20\text{mA}$	-	200	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-6V$, $I_E=0$, $f=1\text{MHz}$	-	13	-	pF

(Note): $h_{FE}(1)$ Classification O:70~140, Y:120~240

$h_{FE}(2)$ Classification O:25Min. Y:40Min.

